

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a SOT186A (TO-220F) "full pack" plastic package. This "series F" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers and logic ICs including microcontrollers in higher noise environments.

2. Features and benefits

- 3Q technology for improved noise immunity
- Direct triggering from low power drivers and logic ICs
- · High commutation capability with maximum false trigger immunity
- High voltage capability
- · Intermediate sensitivity for maximum noise immunity and logic level triggering
- Isolated mounting base package
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

3. Applications

- AC solenoids
- General purpose motor control circuits
- Home appliances

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	M	lin	Тур	Max	Unit
Absolute	maximum rating						
V_{DRM}	repetitive peak off-state voltage		-		-	600	V
$\mathbf{I}_{\mathrm{T(RMS)}}$	RMS on-state current	full sine wave; T _h ≤ 92 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-		-	4	А
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-		-	25	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-		-	27	A
Tj	junction temperature		-		-	125	°C
Static ch	aracteristics						,
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-		-	25	mA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	25	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u>	-	-	25	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	30	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
Dynamic	characteristics	·				
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit	50	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_{D} = 400 \text{ V}; \text{ T}_{\text{j}} = 125 \text{ °C}; \text{ I}_{\text{T(RMS)}} = 4 \text{ A};$ $dV_{\text{com}}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	2.5	-	-	A/ms

5. Pinning information

	Pinning infor			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	NI
2	T2	main terminal 2		T2-T1
3	G	gate		sym051
mb	n.c.	mounting base; isolated	TO-220F (SOT186A)	

6. Ordering information

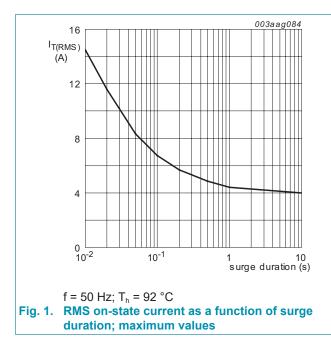
Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BTA204X-600F	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A				

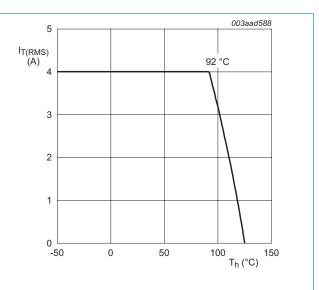
7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

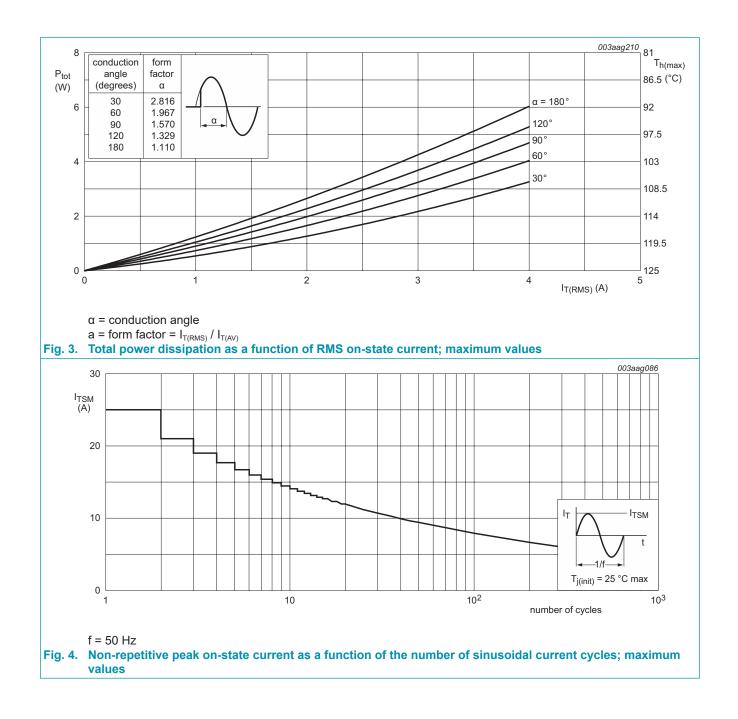
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 92 \degree C$; Fig 1; Fig 2; Fig 3	-	4	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	-	25	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	27	А
l ² t	I ² t for fusing	t _P = 10 ms; SIN	-	3.1	A ² s
dl⊤/dt	rate of rise of on-state current	I _G = 0.2 A	-	100	A/µs
I _{GM}	peak gate current		-	2	А
P_{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		 -	125	°C

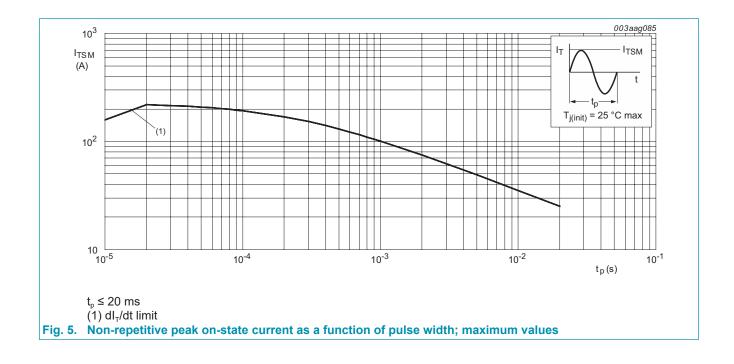






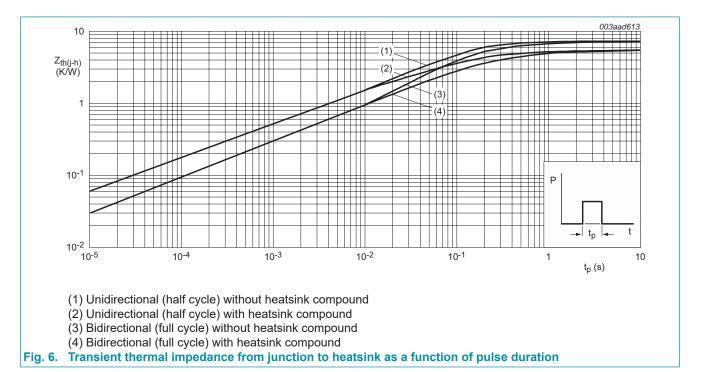
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8. Thermal characteristics

Table 5. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
R _{th(j-h)}	thermal resistance from junction to	full cycle or half cycle; with heatsink compound; Fig 6		-	-	5.5	K/W	
	heatsink	full cycle or half cycle; without heatsink compound; Fig 6		-	-	7.2	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air		-	55	-	K/W	



9. Isolation characteristics

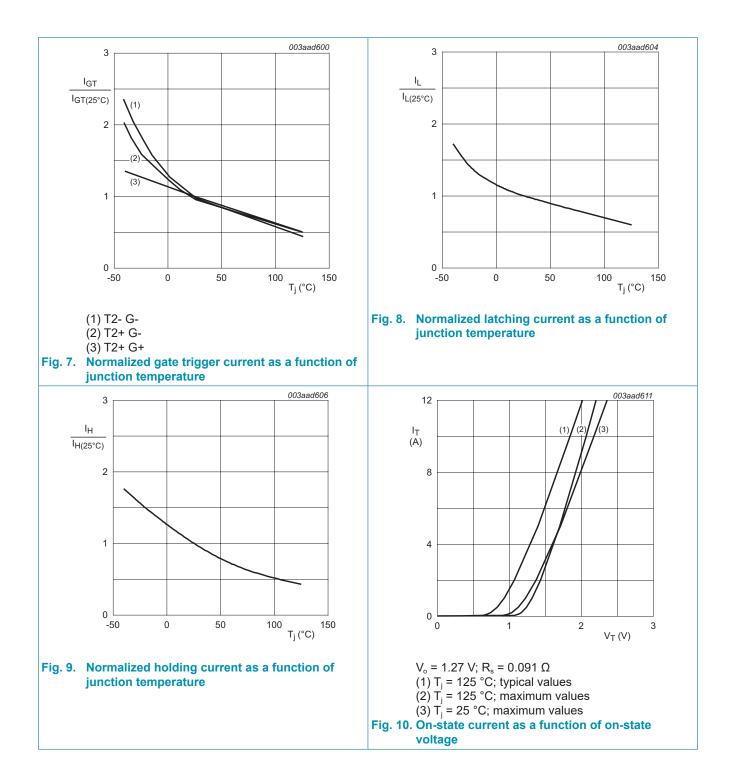
Table 6. Isolation characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C		-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T_h = 25 °C		-	10	-	pF

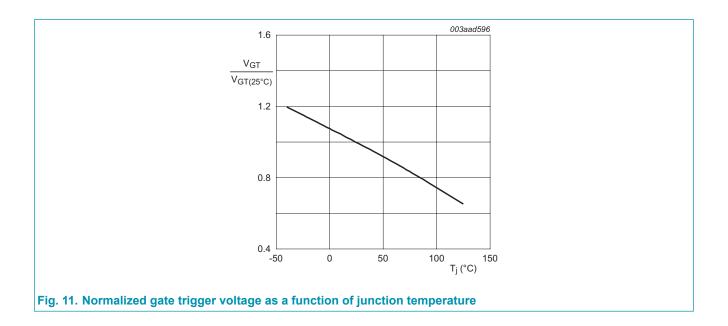
10. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $					
I _{GT}			-	-	25	mA
			-	-	25	mA
			-	-	25	mA
IL	latching current		-	-	30	mA
			-	-	45	mA
			-	-	30	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	30	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
V _{GT}	gate trigger voltage		-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	11	I			
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	50	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	2.5	-	-	A/ms

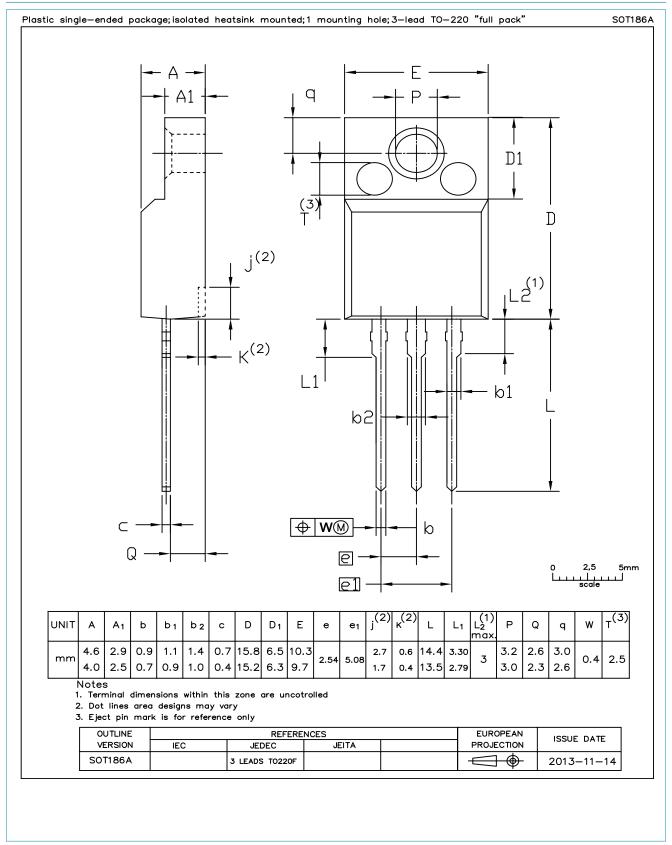
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BTA204X-600F





11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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